TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TD62001P,TD62001AP,TD62001F,TD62001AF,TD62002P TD62002AP,TD62002F,TD62002AF,TD62003P,TD62003AP,TD62003F TD62003AF,TD62004P,TD62004AP,TD62004F,TD62004AF

7CH DARLINGTON SINK DRIVER

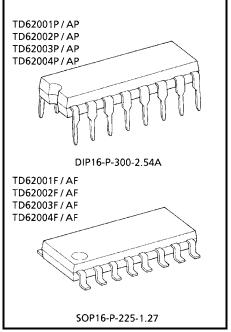
The TD62001P / AP / F / AF Series are high–voltage, high–current darlington drivers comprised of seven NPN darlington pairs. All units feature integral clamp diodes for switching inductive loads.

Applications include relay, hammer, lamp and display (LED) drivers.

FEATURES

- Output current (single output) 500 mA MAX.
- High sustaining voltage output 35 V MIN. (TD62001P / F Series)
 V MIN. (TD62001AP / AF Series)
- Output clamp diodes
- Inputs compatible with various types of logic
- Package Type-P, AP: DIP-16 pin
- Package Type-F, AF: SOP-16 pin

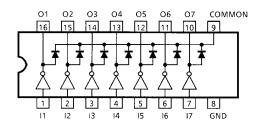
TYPE	INPUT BASE RESISTOR	DESIGNATION		
TD62001P / AP / F / AF	External	General Purpose		
TD62002P / AP / F / AF	10.5-kΩ + 7 V Zenner diode	14~25 V PMOS		
TD62003P / AP / F / AF	2.7 kΩ	TTL, 5 V CMOS		
TD62004P / AP / F / AF	10.5 kΩ	6~15 V PMOS, CMOS		



Weight

DIP16-P-300-2.54A: 1.11 g (Typ.) SOP16-P-225-1.27: 0.16 g (Typ.)

PIN CONNECTION (TOP VIEW)



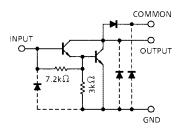
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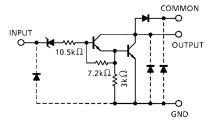
SCHEMATICS (EACH DRIVER)

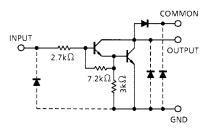
TD62001P / AP / F / AF

TD62002P / AP / F / AF

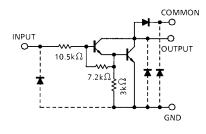
TD62003P / AP / F / AF







TD62004P / AP / F / AF



Note: The input and output parasitic diodes cannot be used as clamp diodes.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTI	SYMBOL	RATING	UNIT		
Output Sustaining	P, F	V	-0.5~35	V	
Voltage	AP, AF	V _{CE} (SUS)	-0.5~50	V	
Output Current		I _{OUT}	500	mA / ch	
Input Voltage	V _{IN} (Note 1)	-0.5~30	V		
Input Current	I _{IN} (Note 2)	25	mA		
Clamp Diode	P, F	V _R	35	V	
Reverse Voltage	AP, AF	۷R	50	V	
Clamp Diode Forward Currer	I _F	500	mA		
	Р		1.0		
Power Dissipation	AP	P _D	1.47	W	
	F, AF		0.54 / 0.625 (Note 3)		
Operating	Р	т	-30~75	°C	
Temperature	AP, F, AF	T _{opr}	-40~85	C	
Storage Temperature		T _{stg}	-55~150	°C	

Note 1: Except TD62001P / AP / F / AF Note 2: Only TD62001P / AP / F / AF

Note 3: On glass epoxy PCB (30 × 30 × 1.6 mm Cu 50%)

2



RECOMMENDED OPERATING CONDITIONS (Ta = -40~85°C and Ta = -30~75°C for only Type-P)

CHARACTERISTIC		SYMBOL	CONDITION		MIN	TYP.	MAX	UNIT
Output Sustaining	P, F	V _{CE} (SUS)			0	_	35	٧
Voltage	AP, AF	VCE (SUS)			0	_	50	
Output Current	AP	Іоит		Duty = 10%	0	_	370	
	AP			Duty = 50%	0	_	130	
	Р		T _{pw} = 25 ms 7 Circuits	Duty = 10%	0	_	295	mA /
	F		Ta = 85°C T _i = 120°C	Duty = 50%	0	_	95	ch
	F, AF		,	Duty = 10%	0	_	233	
	F, AF			Duty = 50%	0	_	70	
Input Voltage	Except TD62001P / AP / F / AF	V _{IN}			0	_	24	V
Input Voltage (Output On)	TD62002	V _{IN} (ON)	I _{OUT} = 400 mA h _{FE} = 800		14.5	_	24	V
	TD62003				2.8	_	24	
(TD62004		F		6.2	_	24	
	TD62001	V _{IN} (OFF)			0	_	0.6	
Input Voltage	TD62002				0	_	7.4	V
(Output Off)	TD62003				0	_	0.7	
	TD62004				0	_	1.0	
Input Current	Only TD62001	I _{IN}			0	_	10	mA
Clamp Diode Reverse	P, F	M			-	_	35	\/
Voltage	AP, AF	V _R				_	50	V
Clamp Diode Forward Current		I _F				_	350	mA
Power Dissipation	Р		Ta = 85°C			_	0.6	
	AP	P_{D}	1a - 65 C		_	_	0.76	W
	AF, F		Ta = 85°C	(Note)	_	_	0.325	

Note: On glass epoxy PCB (30 × 30 × 1.6 mm Cu 50%)

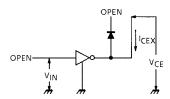


ELECTRICAL CHARACTERISTICS (Ta = 25°C unless otherwise noted)

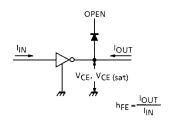
CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST	CONDITION	MIN	TYP.	MAX	UNIT
	AD AE			V _{CE} = 50 V, Ta = 25°C		_	_	50	
Output Leakage	AP, AF			V _{CE} = 50 V, Ta = 85°C		_	_	100	μΑ
	_			V _{CE} = 35 V, Ta = 25°C		_	_	50	
Current	F	I _{CEX}	1	V _{CE} = 35 V, Ta = 85°C		_	_	100	
				V _{CE} = 35 V, Ta = 25°C		_	_	50	
	Р			V _{CE} = 35 V, Ta = 75°C		_	_	100	
	•		2	I _{OUT} = 350 mA, I _{IN} = 500 μA		_	1.3	1.6	
Collector-Emitter Saturation	on Voltage	V _{CE (sat)}		I _{OUT} = 200 i	mA, I _{IN} = 350 μA	_	1.1	1.3	V
				I _{OUT} = 100 i	mA, I _{IN} = 250 μA	_	0.9	1.1	
DC Current Transfer Ratio		hFE	2	V _{CE} = 2 V, I	OUT = 350 mA	1000	_	_	
	TD62002			V _{IN} = 20 V, I _{OUT} = 350 mA		_	1.1	1.7	
Input Current (Output On)	TD62003	I _{IN (ON)}	3	V _{IN} = 2.4 V, I _{OUT} = 350 mA		_	0.4	0.7	mA
,	TD62004			V _{IN} = 9.5 V, I _{OUT} = 350 mA		_	0.8	1.2	
Input Current	Р	lua==	4	I _{OUT} = 500 μA, Ta = 75°C		50	65	_	
(Output Off)	AP, F, AF	I _{IN} (OFF)	4	I _{OUT} = 500 I	µA, Ta = 85°C	50	65	_	μA
	TD62002	003 V _{IN} (ON)			I _{OUT} = 350 mA	_	_	13.7	V
	1002002				I _{OUT} = 200 mA	_	_	11.4	
Input Voltage	TD62003		_	V _{CE} = 2 V	I _{OUT} = 350 mA	_	_	2.6	
(Output On)	1002003		5	5 h _{FE} = 800	I _{OUT} = 200 mA	_	_	2.0	
	TD62004				I _{OUT} = 350 mA	_	_	4.7	
	1002004				I _{OUT} = 200 mA	_	_	4.4	
	AP, AF		6	V _R = 50 V, Ta = 25°C		_	_	50	μA
	AF, AF			V _R = 50 V, Ta = 85°C		_	_	100	
Clamp Diode	F	I_		V _R = 35 V, Ta = 25°C		_	_	50	
Reverse Current	Г	I _R		V _R = 35 V, Ta = 85°C		_	_	100	
	Р			V _R = 35 V, Ta = 25°C		_	_	50	
	P			V _R = 35 V, Ta = 75°C		_	_	100	
Clamp Diode Forward Volt	age	V _F	7	I _F = 350 mA		_	_	2.0	V
Input Capacitance		C _{IN}	<u> </u>			_	15	_	pF
Turn-On Delay	P, F	tou	ton 8		V_{OUT} = 35 V, R _L = 87.5 Ω C _L = 15 pF		0.1	_	
Tuill Oil Dolay	AP, AF	t _{ON}	0	V _{OUT} = 50 V, R _L = 125 Ω C _L = 15 pF		_	0.1	_	- µs
Turn-Off Delay	P, F	torr	8	V_{OUT} = 35 V, R _L = 87.5 Ω C _L = 15 pF		_	0.2	_	
Tuill Oil Delay	AP, AF	t _{OFF} 8		V_{OUT} = 50 V, R_{L} = 125 Ω C_{L} = 15 pF		_	0.2	_	

TEST CIRCUIT

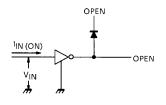
1. I_{CEX}



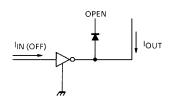
2. V_{CE (sat)}, h_{FE}



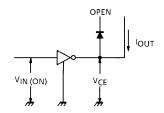
3. IIN (ON)



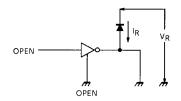
4. I_{IN (OFF)}



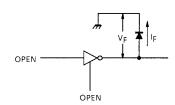
5. V_{IN (ON)}



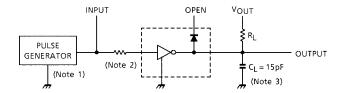
6. I_R

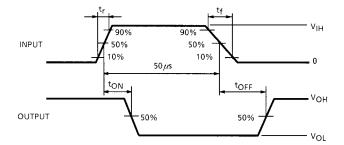


7. V_F



8. ton, toff





Note 1: Pulse width 50 µs, duty cycle 10%

Output impedance 50 Ω , $t_f \le 5$ ns, $t_f \le 10$ ns

Note 2: See below

INPUT CONDITION

TYPE NUMBER	R1	V _{IH}
TD62001P / AP / F / AF	2.7 kΩ	3 V
TD62002P / AP / F / AF	0	13 V
TD62003P / AP / F / AF	0	3 V
TD62004P / AP / F / AF	0	8 V

Note 3: C_L includes probe and jig capacitance.

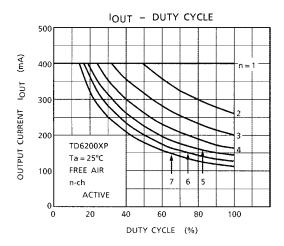
PRECAUTIONS for USING

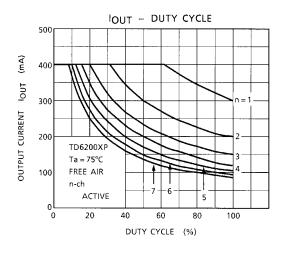
This IC does not include built-in protection circuits for excess current or overvoltage.

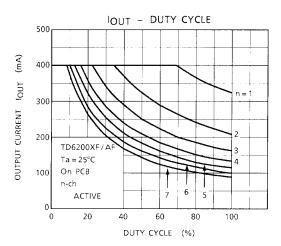
If this IC is subjected to excess current or overvoltage, it may be destroyed.

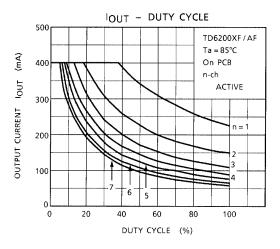
Hence, the utmost care must be taken when systems which incorporate this IC are designed.

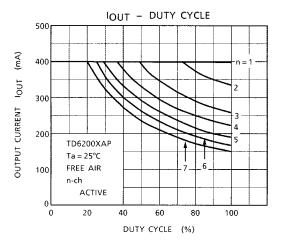
Utmost care is necessary in the design of the output line, COMMON and GND line since IC may be destroyed due to short—circuit between outputs, air contamination fault, or fault by improper grounding.

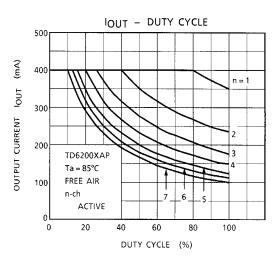




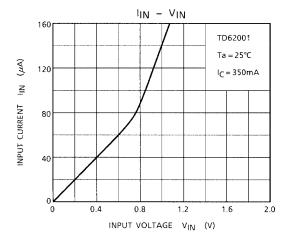


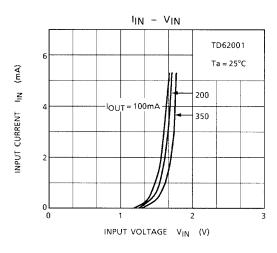


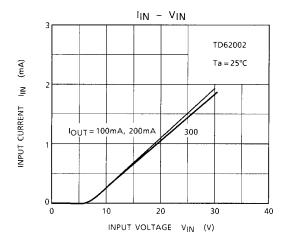


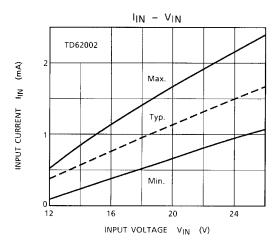


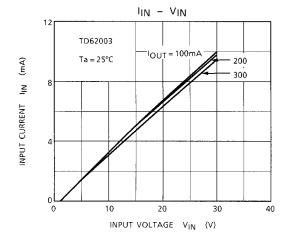
7 2001-06-27

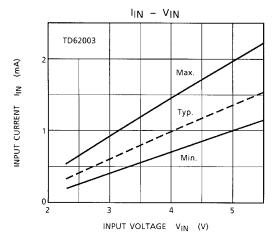




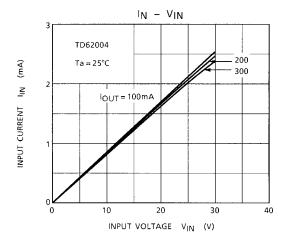


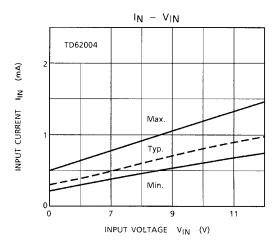


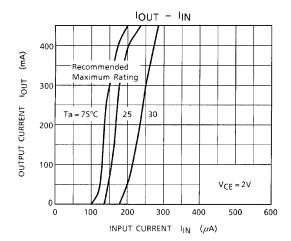


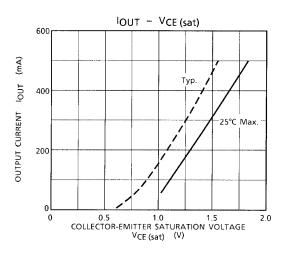


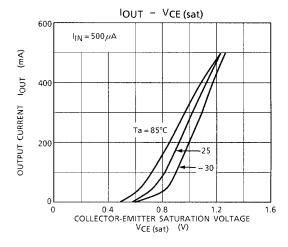
8 2001-06-27

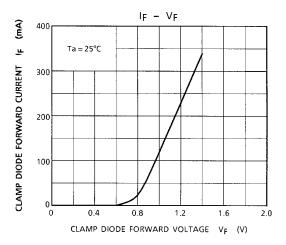




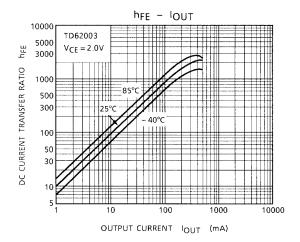


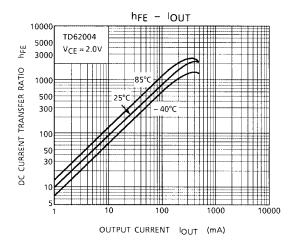


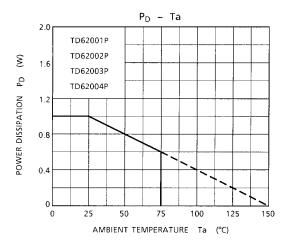


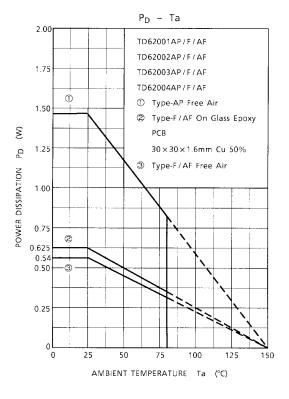


9 2001-06-27









PACKAGE DIMENSIONS

DIP16-P-300-2.54A

Unit : mm

16

17

19.75MAX

19.25±0.2

0.735TYP

1.4±0.1

1.4±0.1

0.5±0.1

0.5±0.1

0.5±0.1

0.5±0.1

0.5±0.1

0.5±0.1

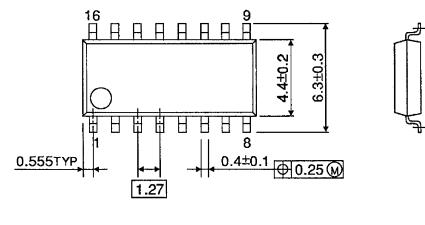
0.5±0.1

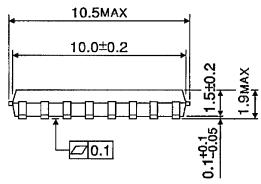
0.5±0.1

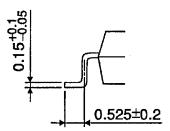
Weight: 1.11 g (Typ.)

PACKAGE DIMENSIONS

SOP16-P-225-1.27 Unit : mm







Weight: 0.16 g (Typ.)

RESTRICTIONS ON PRODUCT USE

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